



Data Sheet

N-Channel MOSFET, 14 A, 650 V, 2+Tab-Pin D2PAK ON Semiconductor

Manufacturers ON Semiconductor, LLC

Package/Case D2PAK

Product Type Transistors

**RoHS** 

Lifecycle

Please submit RFQ for FCB199N65S3 or <a href="mailto:E



Images are for reference only

RFQ

## **General Description**

SUPERFET III MOSFET is ON Semiconductor's brand-new highvoltage super-junction (SJ) MOSFET family that is utilizing chargebalance technology for outstanding low on-resistance and lower gatecharge performance. This advanced technology is tailored to minimizeconduction loss, provide superior switching performance, and withstand extreme dv/dt rate. Consequently, SUPERFET III MOSFET Easy drive series helps manage EMI issues and allows for easier design implementation.

## **Features**

**Application** 

**ONSEMI** 

700 V @>

Higher system reliability at low temperature operation

Ultra Low Gate Charge (Typ.>

Lower switching loss

Low Effective Output Capacitance (Typ.>

Lower switching loss

Optimized Capacitance

Lower peak Vds and lower Vgs oscillation

Internal Gate resistance: 7.0 ohm

Lower peak Vds and lower Vgs oscillation

Typ.>

100% Avalanche Tested

RoHS Compliant

Wave soldering guarantee

## **Related Products**



FCPF11N60F

ON Semiconductor, LLC TO-220F



**FCA47N60** 

ON Semiconductor, LLC TO-3P



FCB20N60TM

ON Semiconductor, LLC D2PAK



**FCP190N65F** 

ON Semiconductor, LLC

TO-220



FCB20N60FTM

ON Semiconductor, LLC

D2PAK



FCB11N60TM

ON Semiconductor, LLC

D2PAK

## FCMT299N60



ON Semiconductor, LLC

4-PowerTSFN



FCMT199N60

ON Semiconductor, LLC

Power-88-4